

Title (en)

SYSTEM AND METHOD FOR FORMING MULTI-COMPONENT DIELECTRIC FILMS

Title (de)

SYSTEM UND VERFAHREN ZUR HERSTELLUNG DIELEKTRISCHER MEHRKOMPONENTENFILME

Title (fr)

SYSTEME ET PROCEDE DE FORMATION DE FILMS DIELECTRIQUES MULTICOMPOSANTS

Publication

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Application

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Priority

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Abstract (en)

[origin: WO2005124849A2] The present invention provides systems and methods for mixing precursors such that a mixture of precursors are present together in a chamber during a single pulse step in an atomic layer deposition (ALD) process to form a multi-component film. The precursors are comprised of at least one different chemical component, and such different components will form a mono-layer to produce a multi-component film. In a further aspect of the present invention, a dielectric film having a composition gradient is provided.

IPC 8 full level

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Citation (search report)

See references of WO 2005124849A2

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